

BAT48

FEATURES :

- For general purpose applications
- These diodes feature very low turn-on voltage and fast switching. These devices are protected by a PN junction guard ring against excessive voltage, such as electrostatic discharges
- This diode is also available in the Mini-MELF case with type designations LL48
- Pb / RoHS Free

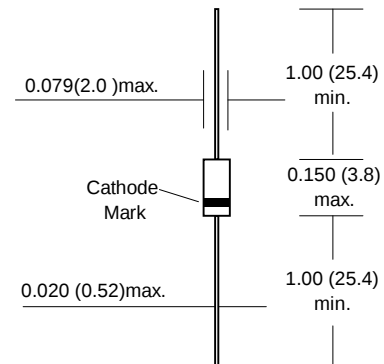
MECHANICAL DATA :

Case: DO-35 Glass Case

Weight: approx. 0.13g

SCHOTTKY BARRIER DIODE

DO - 35 Glass (DO-204AH)



Dimensions in inches and (millimeters)

Maximum Ratings and Thermal Characteristics (Rating at 25 °C ambient temperature unless otherwise specified.)

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	40	V
Continuous Forward Current	I_F	350 ⁽¹⁾	mA
Repetitive Peak Forward Current at $t_p < 1s$,	I_{FRM}	1 ⁽¹⁾	A
Forward Surge Current at $t_p < 10 ms$,	I_{FSM}	7.5 ⁽¹⁾	A
Power Dissipation , $T_a = 65^\circ C$	P_D	330 ⁽¹⁾	mW
Thermal Resistance Junction to Ambient Air	$R_{\theta JA}$	300 ⁽¹⁾	$^\circ C/W$
Junction Temperature	T_J	125	$^\circ C$
Ambient Operating Temperature Range	T_a	-65 to + 125	$^\circ C$
Storage temperature range	T_s	-65 to + 150	$^\circ C$

Note: (1) Valid provided that leads at a distance of 4mm from case are kept at ambient temperature.

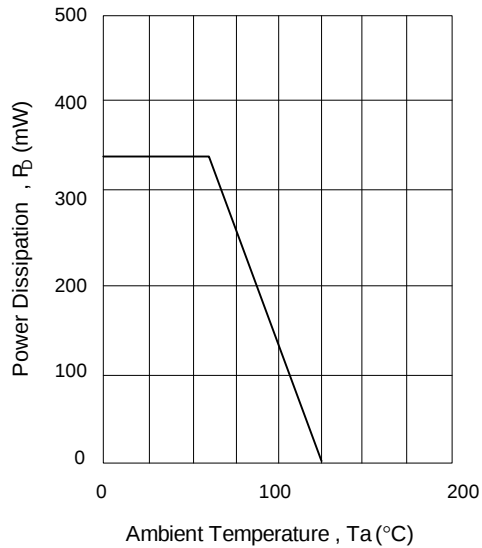
Electrical Characteristics ($T_J = 25^\circ C$ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Breakdown Voltage	$V_{(BR)R}$	$I_R = 100 \mu A$ (pulsed)	40	-	-	V
Reverse Current	I_R	$V_R = 10 V$	-	-	2	μA
Pulse Test $t_p < 300 \mu s$, $\delta < 2\%$		$V_R = 20 V$	-	-	5	
		$V_R = 40 V$	-	-	25	
Forward Voltage	V_F	$I_F = 1mA$	-	-	0.30	V
		$I_F = 10mA$	-	-	0.40	
Pulse Test $t_p < 300 \mu s$, $\delta < 2\%$		$I_F = 30mA$	-	-	0.50	
		$I_F = 100mA$	-	-	0.75	
		$I_F = 500mA$	-	-	0.90	
Diode Capacitance	C_d	$V_R = 1V$, $f = 1MHz$	-	12	-	pF

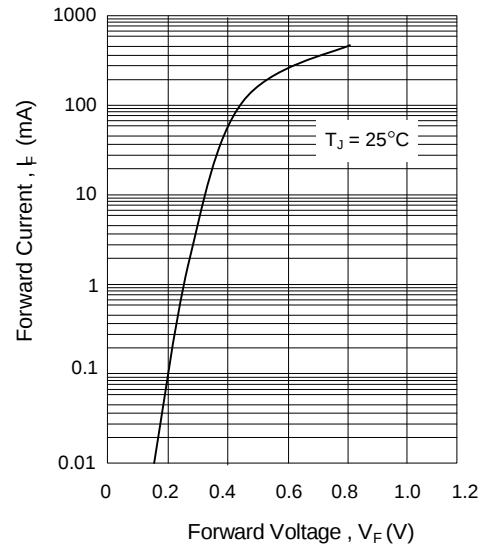


RATING AND CHARACTERISTIC CURVES (BAT48)

**Admissible Power Dissipation
vs. Ambient Temperature**



Typical Forward Characteristics



Typical Reverse Characteristics

